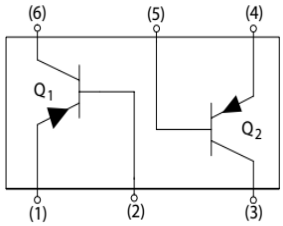
SOT-363 PNP

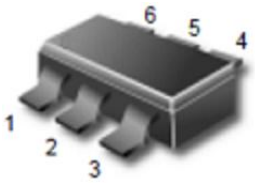
Double silicon PNP transistor in a SOT-363 Plastic Package

600mA

Collector currents to 600mA. HF Product.

General purpose amplifier.





PIN 1 4 Emitter PIN 2 5 Base PIN 3 6 Collector

&

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-60	V
Collector to Emitter Voltage	V_{CEO}	-60	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current	I_C	-600	mA
Collector Power Dissipation	P_C	350	mW
Junction Temperature	T_j	150	

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2F **
*

● “1”

2F

***:

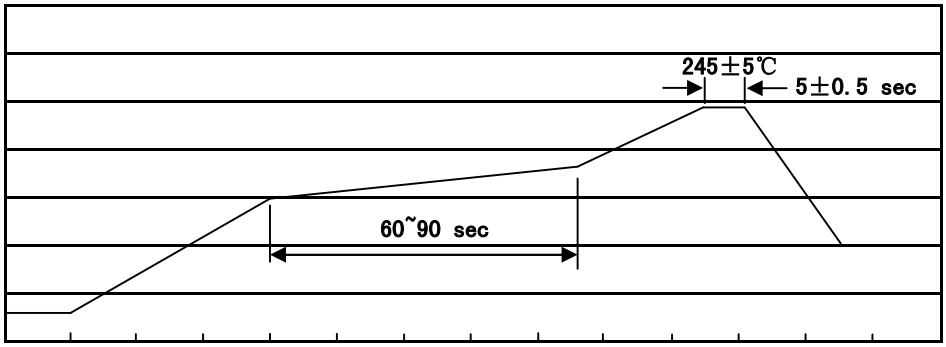
Note:

● “1” Pin

2F Product Type Code

***: Lot No. Code, code change with Lot No.

H K&&*&& Temperature Profile for IR Reflow Soldering(Pb-Free)



				Note:
1	150	180	60 90sec;	1.Preheating:150~180℃, Time:60~90sec.
2	245±5		5±0.5sec;	2.Peak Temp.:245±5℃, Duration:5±0.5sec.
3		2	10℃/sec.	3. Cooling Speed: 2~10℃/sec.

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260±5℃	10±1 sec.	Temp.:260±5℃	Time:10±1 sec

&&*&&D:2?:@.=@&'D)8%&

%& / REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm^3)		
							盒	箱
						〃		

&&*&&P3<.2,/&